

NE5533/5533A NE/SA/SE5534/5534A Dual and Single Low Noise Op Amp

Linear Products

Product Specification

DESCRIPTION

The 5533/5534 are dual and single high-performance low noise operational amplifiers. Compared to other operational amplifiers, such as TL083, they show better noise performance, improved output drive capability and considerably higher small-signal and power bandwidths.

This makes the devices especially suitable for application in high quality and professional audio equipment, in instrumentation and control circuits and telephone channel amplifiers. The op amps are internally compensated for gain equal to, or higher than, three. The frequency response can be optimized with an external compensation capacitor for various applications (unity gain amplifier, capacitive load, slew rate, low overshoot, etc.) If very low noise is of prime importance, it is recommended that the 5533A/5534A version be used which has guaranteed noise specifications.

FEATURES

- Small-signal bandwidth: 10MHz
- Output drive capability: 600Ω, 10V_{RMS} at V_S = ±18V
- Input noise voltage: 4nV/√Hz
- DC voltage gain: 100000
- AC voltage gain: 6000 at 10kHz
- Power bandwidth: 200kHz
- Slew rate: 13V/μs
- Large supply voltage range: ±3 to ±20V
- 5534 MIL-STD processing available

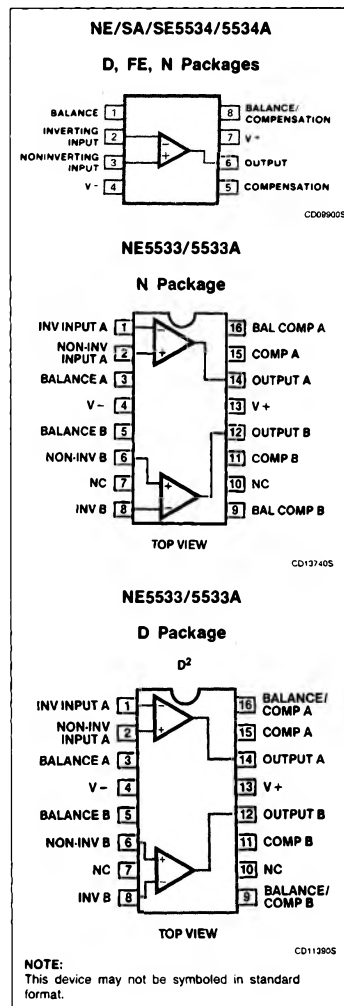
APPLICATIONS

- Audio equipment
- Instrumentation and control circuits
- Telephone channel amplifiers
- Medical equipment

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE
14-Pin Plastic DIP	0 to +70°C	NE5533N
16-Pin Plastic SO package	0 to +70°C	NE5533AD
14-Pin Plastic DIP	0 to +70°C	NE5533AN
16-Pin Plastic SO package	0 to +70°C	NE5533D
8-Pin Plastic SO package	0 to +70°C	NE5534D
8-Pin Hermetic Cerdip	0 to +70°C	NE5534FE
8-Pin Plastic DIP	0 to +70°C	NE5534N
8-Pin Plastic SO package	0 to +70°C	NE5534AD
8-Pin Hermetic Cerdip	0 to +70°C	NE5534AFE
8-Pin Plastic DIP	0 to +70°C	NE5534AN
8-Pin Plastic DIP	-40°C to +85°C	SA5534N
8-Pin Plastic SO package	-40°C to +85°C	SA5534AD
8-Pin Plastic DIP	-40°C to +85°C	SA5534AN
8-Pin Hermetic Cerdip	-55°C to +125°C	SE5534AFE
8-Pin Plastic DIP	-55°C to +125°C	SE5534N
8-Pin Hermetic Cerdip	-55°C to +125°C	SE5534AFE
8-Pin Plastic DIP	-55°C to +125°C	SE5534AN

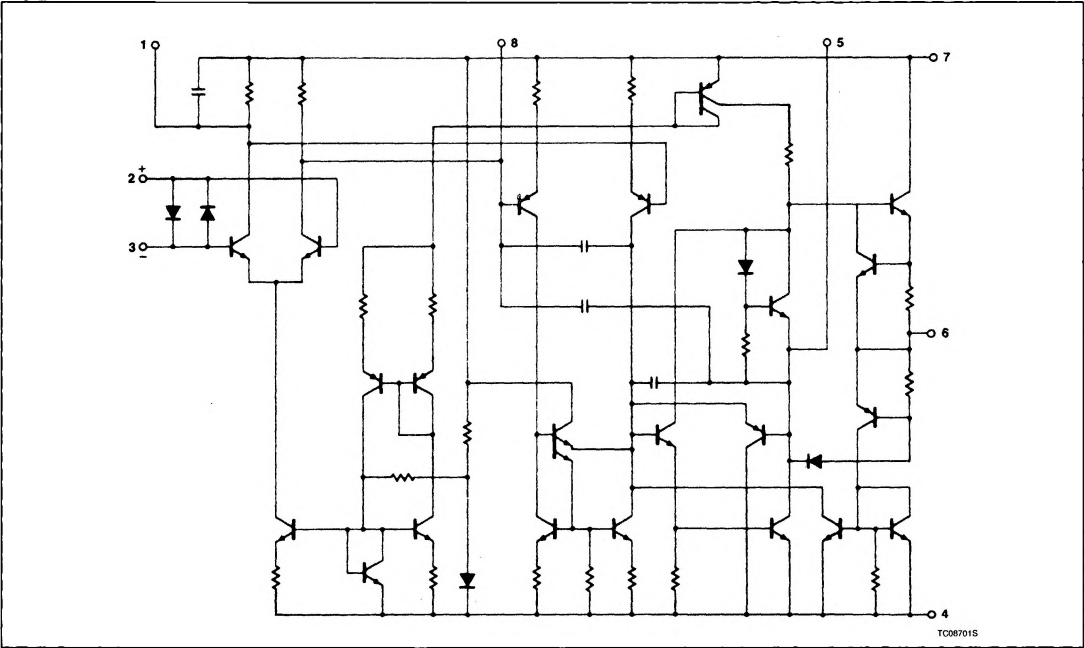
PIN CONFIGURATIONS



Dual and Single Low
Noise Op Amp

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NE/SA/SE5534/5534A

EQUIVALENT SCHEMATIC



Dual and Single Low Noise Op Amp

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ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_S	Supply voltage	± 22	V
V_{IN}	Input voltage	$\pm V$ supply	V
V_{DIFF}	Differential input voltage ¹	± 0.5	V
T_A	Operating temperature range		
	SE	-55 to +125	°C
	SA	-40 to +85	°C
	NE	0 to +70	°C
T_{STG}	Storage temperature range	-65 to +150	°C
T_J	Junction temperature	150	°C
P_D	Power dissipation at 25°C ²		
	5533D	1350	mW
	5533N	1500	mW
	5534D	750	mW
	5534FE	800	mW
	5534N	1150	mW
	Output short-circuit duration ³	Indefinite	
T_{SOLD}	Lead soldering temperature (10sec max)	300	°C

NOTES:

- Diodes protect the inputs against over voltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input voltage exceeds 0.6V. Maximum current should be limited to ± 10 mA.
- For operation at elevated temperature, derate packages based on the following junction-to-ambient thermal resistance:
 8-pin ceramic DIP 150°C/W
 8-pin plastic DIP 105°C/W
 8-pin plastic SO 160°C/W
 14-pin plastic DIP 80°C/W
 16-pin plastic SO 90°C/W
- Output may be shorted to ground at $V_S = \pm 15$ V, $T_A = 25^\circ\text{C}$. Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

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DC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified.^{1, 2, 3}

SYMBOL	PARAMETER	TEST CONDITIONS	SE5534/5534A			NE5533/5533A NE/SA5534/5534A			UNIT
			Min	Typ	Max	Min	Typ	Max	
V_{OS}	Offset voltage	Over temperature		0.5	2		0.5	4	mV
$\Delta V_{OS}/\Delta T$				5	3		5	5	mV/ $\mu\text{V}/^\circ\text{C}$
I_{OS}	Offset current	Over temperature		10	200		20	300	nA
$\Delta I_{OS}/\Delta T$				200	500		200	400	nA/ $\text{pA}/^\circ\text{C}$
I_B	Input current	Over temperature		400	800		500	1500	nA
$\Delta I_B/\Delta T$				5	1500		5	2000	nA/ $\text{nA}/^\circ\text{C}$
I_{CC}	Supply current per op amp	Over temperature		4	6.5		4	8	mA
V_{CM}	Common mode input range		± 12	± 13		± 12	± 13		V
CMRR	Common mode rejection ratio		80	100		70	100		dB
PSRR	Power supply rejection ratio			10	50		10	100	$\mu\text{V}/\text{V}$
A_{VOL}	Large-signal voltage gain	$R_L \geq 600\Omega$, $V_O = \pm 10\text{V}$ Over temperature	50 25	100		25 15	100		V/mV V/mV
V_{OUT}	Output swing	$R_L \geq 600\Omega$	± 12	± 13		± 12	± 13		V
		Over temperature	± 10	± 12		± 10	± 12		V
		$R_L \geq 600\Omega$, $V_S = \pm 18\text{V}$	± 15	± 16		± 15	± 16		V
		$R_L \geq 2\text{k}\Omega$	± 13	± 13.5		± 13	± 13.5		V
		Over temperature	± 12	± 12.5		± 12	± 12.5		V
R_{IN}	Input resistance		50	100		30	100		k Ω
I_{SC}	Output short circuit current			38			38		mA

NOTES:

1. For NE5533/5533A/5534/5534A, $T_{MIN} = 0^\circ\text{C}$, $T_{MAX} = 70^\circ\text{C}$.
2. For SE5534/5534A, $T_{MIN} = -55^\circ\text{C}$, $T_{MAX} = +125^\circ\text{C}$.
3. For SA5534/5534A, $T_{MIN} = -40^\circ\text{C}$, $T_{MAX} = +125^\circ\text{C}$.

Dual and Single Low Noise Op Amp

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AC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	SE5534/5534A			NE5533/5533A NESA5534/5534A			UNIT
			Min	Typ	Max	Min	Typ	Max	
R_{OUT}	Output resistance	$A_V = 30\text{dB}$ closed-loop $f = 10\text{kHz}$, $R_L = 600\Omega$, $C_C = 22\text{pF}$		0.3			0.3		Ω
	Transient response	Voltage-follower, $V_{IN} = 50\text{mV}$ $R_L = 600\Omega$, $C_C = 22\text{pF}$, $C_L = 100\text{pF}$							
t_R	Rise time			20			20		ns
	Overshoot			20			20		%
	Transient response	$V_{IN} = 50\text{mV}$, $R_L = 600\Omega$ $C_C = 47\text{pF}$, $C_L = 500\text{pF}$							
t_R	Rise time			50			50		ns
	Overshoot			35			35		%
A_V	Gain	$f = 10\text{kHz}$, $C_C = 0$ $f = 10\text{kHz}$, $C_C = 22\text{pF}$		6 2.2			6 2.2		V/mV V/mV
GBW	Gain bandwidth product	$C_C = 22\text{pF}$, $C_L = 100\text{pF}$		10			10		MHz
SR	Slew rate	$C_C = 0$ $C_C = 22\text{pF}$		13 6			13 6		V/ μs V/ μs
	Power bandwidth	$V_{OUT} = \pm 10\text{V}$, $C_C = 0$ $V_{OUT} = \pm 10\text{V}$, $C_C = 22\text{pF}$ $V_{OUT} = \pm 14\text{V}$, $R_L = 600\Omega$ $C_C = 22\text{pF}$, $V_{CC} = \pm 18\text{V}$		200 95 70			200 95 70		kHz kHz kHz

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = 15\text{V}$, unless otherwise specified.

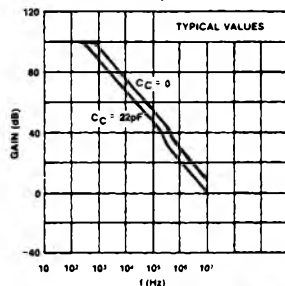
SYMBOL	PARAMETER	TEST CONDITIONS	5533/5534			5533A/5534A			UNIT
			Min	Typ	Max	Min	Typ	Max	
V_{NOISE}	Input noise voltage	$f_O = 30\text{Hz}$ $f_O = 1\text{kHz}$		7 4			5.5 3.5	7 4.5	nV/ $\sqrt{\text{Hz}}$ nV/ $\sqrt{\text{Hz}}$
I_{NOISE}	Input noise current	$f_O = 30\text{Hz}$ $f_O = 1\text{kHz}$		2.5 0.6			1.5 0.4		pA/ $\sqrt{\text{Hz}}$ pA/ $\sqrt{\text{Hz}}$
	Broadband noise figure	$f = 10\text{Hz} - 20\text{kHz}$, $R_S = 5\text{k}\Omega$					0.9		dB
	Channel separation	$f = 1\text{kHz}$, $R_S = 5\text{k}\Omega$		110			110		dB

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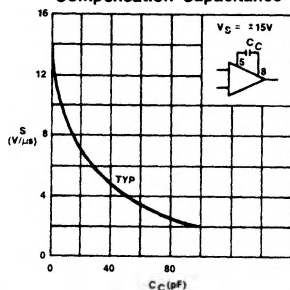
TYPICAL PERFORMANCE CHARACTERISTICS

Open-Loop Frequency Response



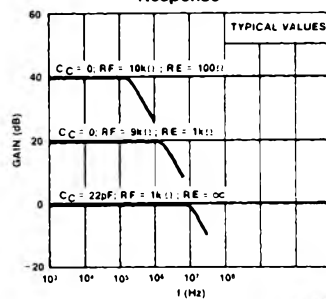
QP050905

Slew Rate as a Function of Compensation Capacitance



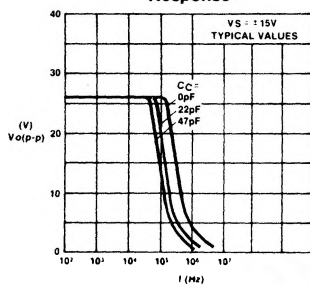
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Closed-Loop Frequency Response



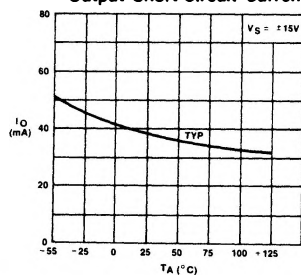
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Large-Signal Frequency Response



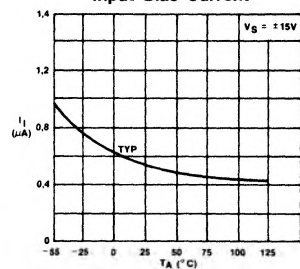
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Output Short-Circuit Current



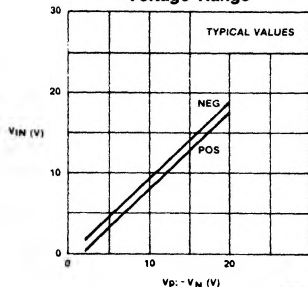
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Input Bias Current



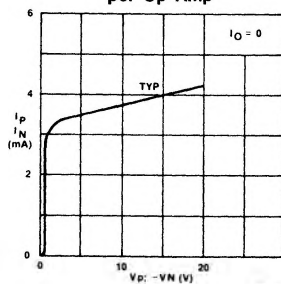
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Input Common-Mode Voltage Range



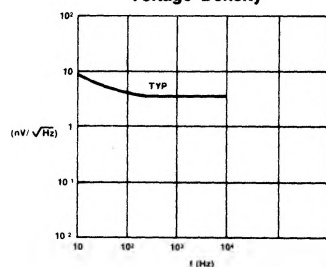
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Supply Current per Op Amp



QP051305

Input Noise Voltage Density

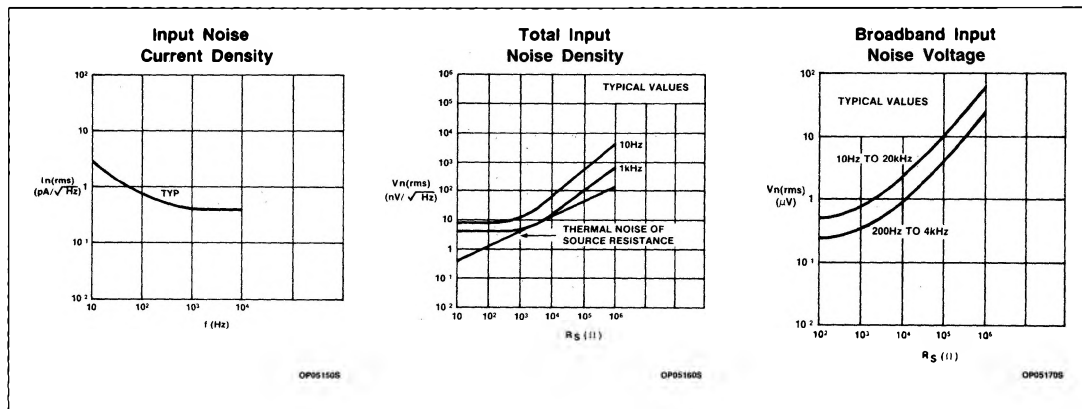


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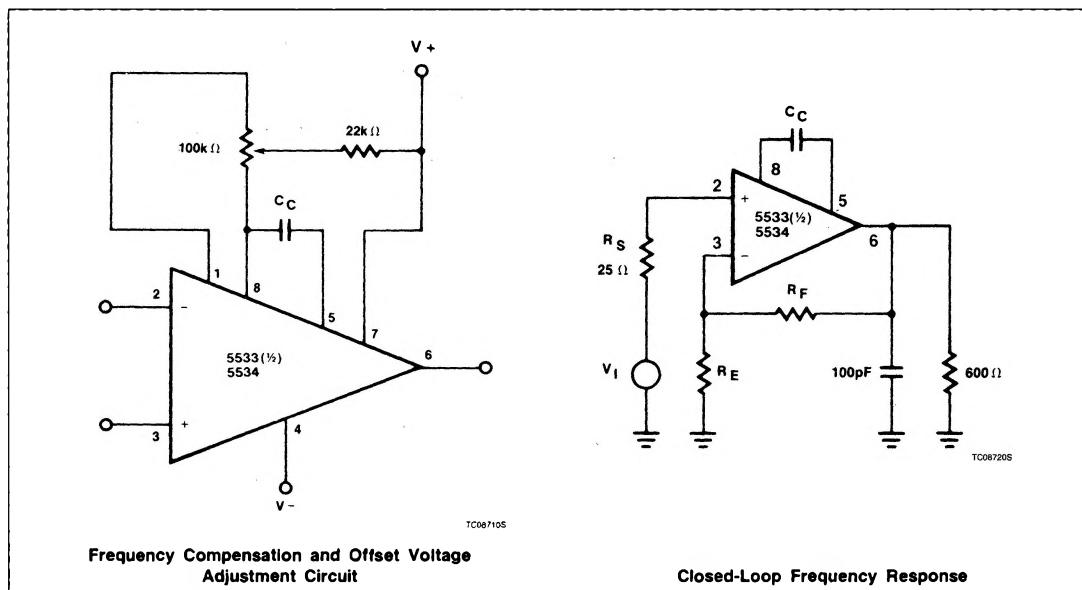
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TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



TEST LOAD CIRCUITS



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NOISE TEST BLOCK DIAGRAM

